

MC14007UB

Dual Complementary Pair Plus Inverter

The MC14007UB multipurpose device consists of three N-Channel and three P-Channel enhancement mode devices packaged to provide access to each device. These versatile parts are useful in inverter circuits, pulse-shapers, linear amplifiers, high input impedance amplifiers, threshold detectors, transmission gating, and functional gating.

Features

- Diode Protection on All Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low-power TTL Loads or One Low-power Schottky TTL Load Over the Rated Temperature Range
- Pin-for-Pin Replacement for CD4007A or CD4007UB
- This device has 2 outputs without ESD Protection. Antistatic precautions must be taken.
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (Voltages Referenced to V_{SS})

Symbol	Parameter	Value	Unit
V _{DD}	DC Supply Voltage Range	-0.5 to +18.0	V
V _{in} , V _{out}	Input or Output Voltage Range (DC or Transient)	-0.5 to V _{DD} + 0.5	V
I _{in} , I _{out}	Input or Output Current (DC or Transient) per Pin	±10	mA
P _D	Power Dissipation, per Package (Note 1)	500	mW
T _A	Ambient Temperature Range	-55 to +125	°C
T _{stg}	Storage Temperature Range	-65 to +150	°C
T _L	Lead Temperature (8 second Soldering)	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Temperature Derating:

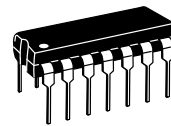
Plastic "P and D/DW" Packages: - 7.0 mW/°C from 65°C to 125°C.



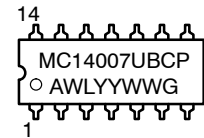
ON Semiconductor®

<http://onsemi.com>

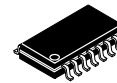
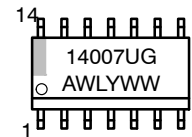
MARKING DIAGRAMS



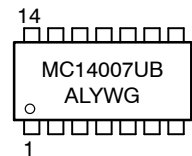
PDIP-14
P SUFFIX
CASE 646



SOIC-14
D SUFFIX
CASE 751A

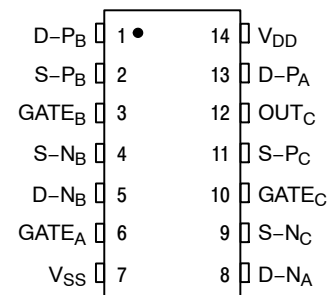


SOEIAJ-14
F SUFFIX
CASE 965



A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week
G = Pb-Free Indicator

PIN ASSIGNMENT



D = DRAIN
S = SOURCE

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

MC14007UB

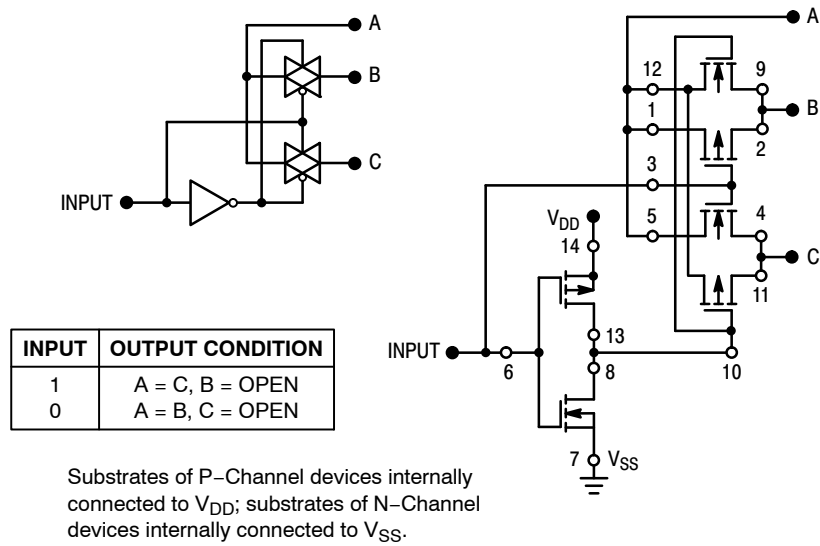


Figure 1. Typical Application: 2-Input Analog Multiplexer

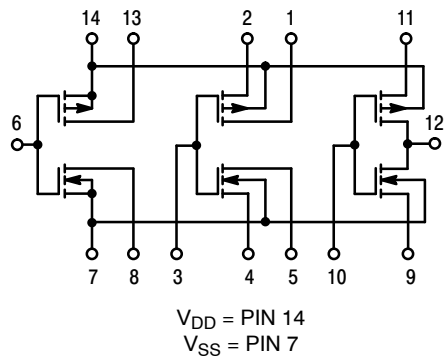


Figure 2. Schematic

MC14007UB

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

Symbol	Characteristic	V _{DD} Vdc	-55°C		25°C			125°C		Unit	
			Min	Max	Min	Typ (Note 2)	Max	Min	Max		
V _{OL}	Output Voltage "0" Level V _{in} = V _{DD} or 0	5.0	-	0.05	-	0	0.05	-	0.05	Vdc	
		10	-	0.05	-	0	0.05	-	0.05		
		15	-	0.05	-	0	0.05	-	0.05		
V _{OH}	V _{in} = 0 or V _{DD} "1" Level	5.0	4.95	-	4.95	5.0	-	4.95	-	Vdc	
		10	9.95	-	9.95	10	-	9.95	-		
		15	14.95	-	14.95	15	-	14.95	-		
V _{IL}	Input Voltage "0" Level (V _O = 4.5 Vdc) (V _O = 9.0 Vdc) (V _O = 13.5 Vdc)	5.0	-	1.0	-	2.25	1.0	-	1.0	Vdc	
		10	-	2.0	-	4.50	2.0	-	2.0		
		15	-	2.5	-	6.75	2.5	-	2.5		
V _{IH}	(V _O = 0.5 Vdc) (V _O = 1.0 Vdc) (V _O = 1.5 Vdc) "1" Level	5.0	4.0	-	4.0	2.75	-	4.0	-	Vdc	
		10	8.0	-	8.0	5.50	-	8.0	-		
		15	12.5	-	12.5	8.25	-	12.5	-		
I _{OH}	Output Drive Current Source (V _{OH} = 2.5 Vdc) (V _{OH} = 4.6 Vdc) (V _{OH} = 9.5 Vdc) (V _{OH} = 13.5 Vdc)	5.0	-3.0	-	-2.4	-5.0	-	-1.7	-	mAdc	
		5.0	-0.64	-	-0.51	-1.0	-	-0.36	-		
		10	-1.6	-	-1.3	-2.5	-	-0.9	-		
		15	-4.2	-	-3.4	-10	-	-2.4	-		
I _{OL}	(V _{OL} = 0.4 Vdc) (V _{OL} = 0.5 Vdc) (V _{OL} = 1.5 Vdc) Sink	5.0	0.64	-	0.51	1.0	-	0.36	-	mAdc	
		10	1.6	-	1.3	2.5	-	0.9	-		
		15	4.2	-	3.4	10	-	2.4	-		
I _{in}	Input Current	15	-	±0.1	-	±0.00001	±0.1	-	±1.0	μAdc	
C _{in}	Input Capacitance (V _{in} = 0)	-	-	-	-	5.0	7.5	-	-	pF	
I _{DD}	Quiescent Current (Per Package)	5.0	-	0.25	-	0.0005	0.25	-	7.5	μAdc	
		10	-	0.5	-	0.0010	0.5	-	15		
		15	-	1.0	-	0.0015	1.0	-	30		
I _T	Total Supply Current (Notes 3 and 4) (Dynamic plus Quiescent, Per Gate) (C _L = 50 pF)	5.0	I _T = (0.7 μA/kHz) f + I _{DD} /6								μAdc
10	I _T = (1.4 μA/kHz) f + I _{DD} /6										
15	I _T = (2.2 μA/kHz) f + I _{DD} /6										

2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

3. The formulas given are for the typical characteristics only at 25°C.

4. To calculate total supply current at loads other than 50 pF: I_T(C_L) = I_T(50 pF) + (C_L - 50) Vfk

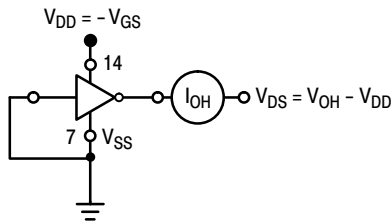
where: I_T is in μA (per package), C_L in pF, V = (V_{DD} - V_{SS}) in volts, f in kHz is input frequency, and k = 0.003.

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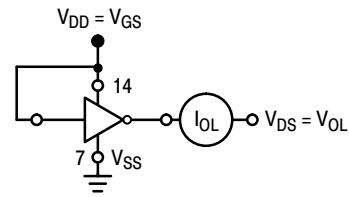
SWITCHING CHARACTERISTICS (Note 5) ($C_L = 50 \text{ pF}$, $T_A = 25^\circ\text{C}$)

Symbol	Characteristic	V_{DD} Vdc	Min	Typ (Note 6)	Max	Unit
t_{TLH}	Output Rise Time $t_{TLH} = (1.2 \text{ ns/pF}) C_L + 30 \text{ ns}$ $t_{TLH} = (0.5 \text{ ns/pF}) C_L + 20 \text{ ns}$ $t_{TLH} = (0.4 \text{ ns/pF}) C_L + 15 \text{ ns}$	5.0	-	90	180	ns
		10	-	45	90	
		15	-	35	70	
t_{THL}	Output Fall Time $t_{THL} = (1.2 \text{ ns/pF}) C_L + 15 \text{ ns}$ $t_{THL} = (0.5 \text{ ns/pF}) C_L + 15 \text{ ns}$ $t_{THL} = (0.4 \text{ ns/pF}) C_L + 10 \text{ ns}$	5.0	-	75	150	ns
		10	-	40	80	
		15	-	30	60	
t_{PLH}	Turn-Off Delay Time $t_{PLH} = (1.5 \text{ ns/pF}) C_L + 35 \text{ ns}$ $t_{PLH} = (0.2 \text{ ns/pF}) C_L + 20 \text{ ns}$ $t_{PLH} = (0.15 \text{ ns/pF}) C_L + 17.5 \text{ ns}$	5.0	-	60	125	ns
		10	-	30	75	
		15	-	25	55	
t_{PHL}	Turn-On Delay Time $t_{PHL} = (1.0 \text{ ns/pF}) C_L + 10 \text{ ns}$ $t_{PHL} = (0.3 \text{ ns/pF}) C_L + 15 \text{ ns}$ $t_{PHL} = (0.2 \text{ ns/pF}) C_L + 15 \text{ ns}$	5.0	-	60	125	ns
		10	-	30	75	
		15	-	25	55	

5. The formulas given are for the typical characteristics only. Switching specifications are for device connected as an inverter.
6. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.



All unused inputs connected to ground.



All unused inputs connected to ground.

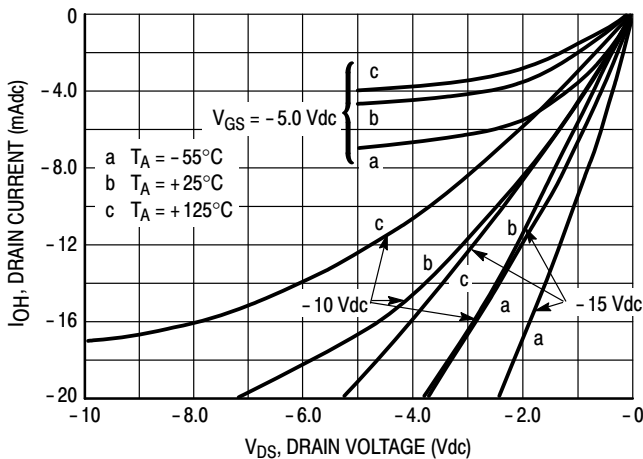


Figure 3. Typical Output Source Characteristics

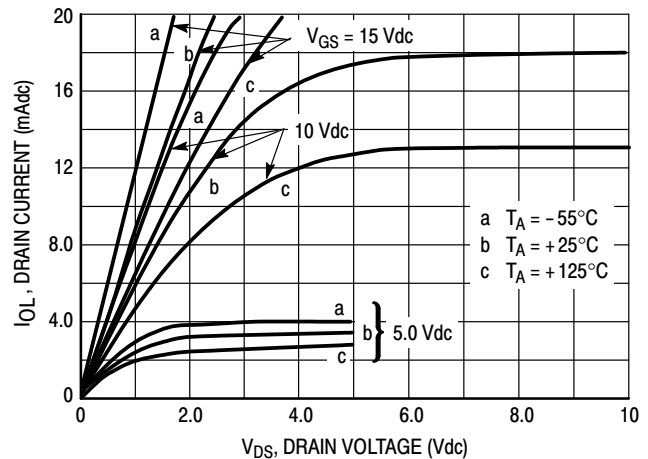


Figure 4. Typical Output Sink Characteristics

These typical curves are not guarantees, but are design aids.
Caution: The maximum current rating is 10 mA per pin.

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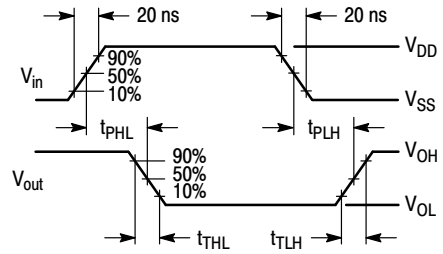
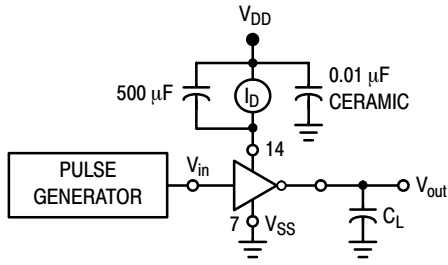
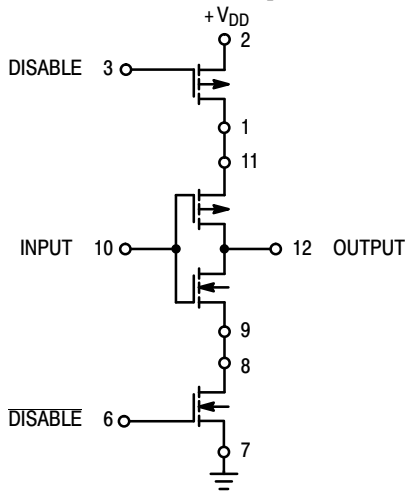


Figure 5. Switching Time and Power Dissipation Test Circuit and Waveforms

APPLICATIONS

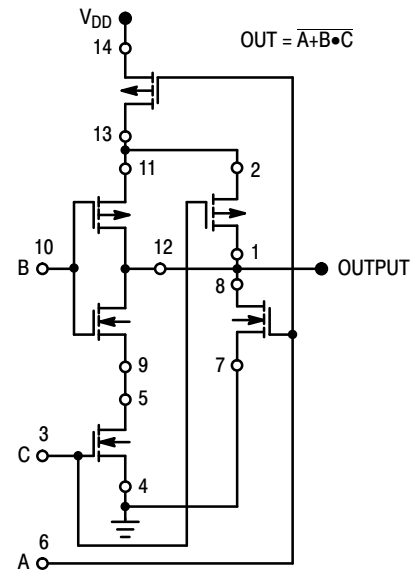
The MC14007UB dual pair plus inverter, which has access to all its elements offers a number of unique circuit applications. Figures 1, 6, and 7 are a few examples of the device flexibility.



INPUT	DISABLE	OUTPUT
1	0	0
0	0	1
X	1	OPEN

X = Don't Care

Figure 6. 3-State Buffer



Substrates of P-Channel devices internally connected to V_{DD} ;
Substrates of N-Channel devices internally connected to V_{SS} .

Figure 7. AOI Functions Using Tree Logic

MC14007UB

ORDERING INFORMATION

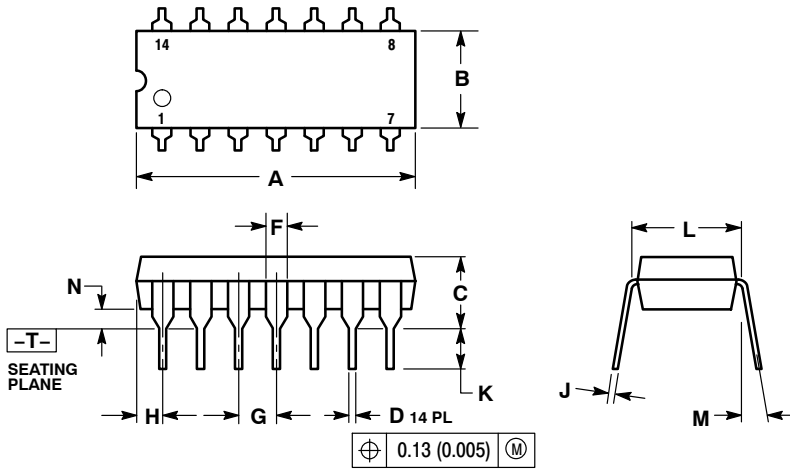
Device	Package	Shipping†
MC14007UBCPG	PDIP-14 (Pb-Free)	25 Units / Rail
MC14007UBDG	SOIC-14 (Pb-Free)	55 Units / Rail
MC14007UBDR2G	SOIC-14 (Pb-Free)	2500 / Tape & Reel
MC14007UBFELG	SOEIAJ-14 (Pb-Free)	2000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MC14007UB

PACKAGE DIMENSIONS

PDIP-14
CASE 646-06
ISSUE P



NOTES:

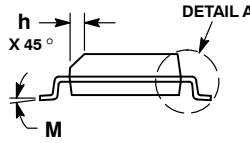
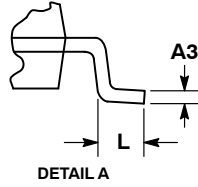
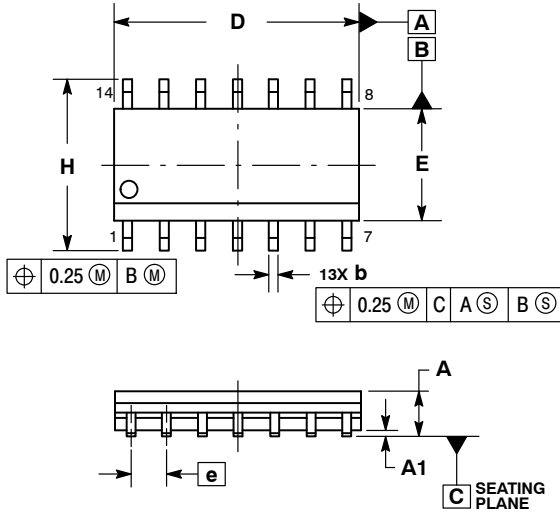
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.715	0.770	18.16	19.56
B	0.240	0.260	6.10	6.60
C	0.145	0.185	3.69	4.69
D	0.015	0.021	0.38	0.53
F	0.040	0.070	1.02	1.78
G	0.100 BSC		2.54 BSC	
H	0.052	0.095	1.32	2.41
J	0.008	0.015	0.20	0.38
K	0.115	0.135	2.92	3.43
L	0.290	0.310	7.37	7.87
M	---	10°	---	10°
N	0.015	0.039	0.38	1.01

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PACKAGE DIMENSIONS

SOIC-14 NB
CASE 751A-03
ISSUE K

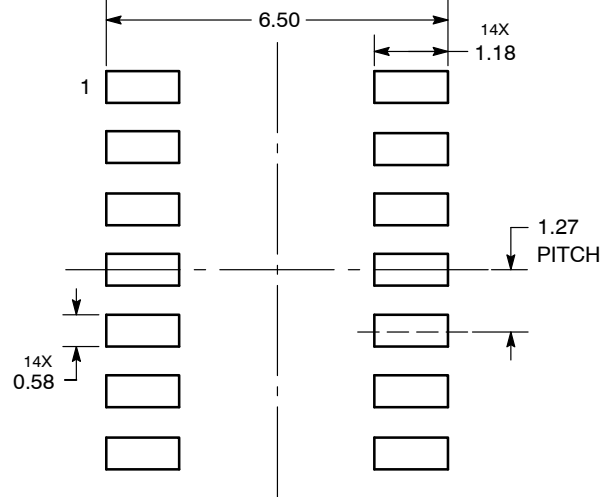


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
A3	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
L	0.40	1.25	0.016	0.049
M	0°	7°	0°	7°

SOLDERING FOOTPRINT*



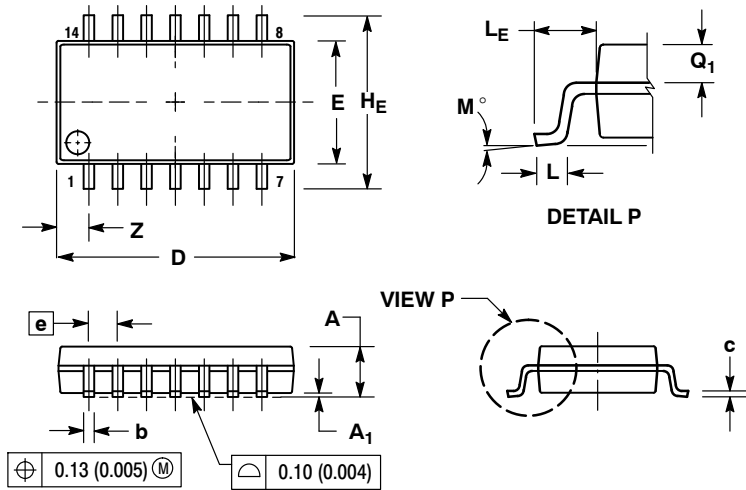
DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MC14007UB

PACKAGE DIMENSIONS

SOEIAJ-14
CASE 965-01
ISSUE B



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	---	2.05	---	0.081
A ₁	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.10	0.20	0.004	0.008
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
HE	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
LE	1.10	1.50	0.043	0.059
M	0°	10°	0°	10°
Q ₁	0.70	0.90	0.028	0.035
Z	---	1.42	---	0.056

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- Подбор аналогов;
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- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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